

Using the TPS51916EVM-746 Complete DDR2, DDR3, DDR3L, and DDR4 Memory Power Solution Synchronous Buck Controller, 2-A LDO, Buffered Reference

The TPS51916EVM-746 evaluation module (EVM) allows users to evaluate the performance of the TPS51916 low-dropout (LDO) regulator. The TPS51916 provides a complete power supply for DDR2, DDR3, DDR3L, and DDR4 memory system in the lowest total cost and minimum space. TPS51916 integrates a synchronous buck controller (VDDQ) with a 2-A sink/source tracking LDO (VTT) and buffered, low-noise reference (VTTREF).

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1 Description

The TPS51916EVM-746 is designed to use a regulated 12-V bus to produce a regulated 1.5-VDDQ output at up to a 20-A load current. The TPS51916EVM-746 demonstrates TPS51916 in a typical DDR3 application with D-CAP2™-mode operation. The EVM also provides test points to evaluate the performance of the TPS51916.

1.1 Typical Applications

- DDR2/DDR2/DDR3L/DDR4 memory power supplies
- SSTL_18, SSTL_15, SSTL_135, and HSTL termination

1.2 Features

The TPS51916EVM-746 features:

- D-CAP2™-mode operation with all-ceramic VDDQ output capacitor
- 20-Adc steady-state VDDQ output current
- Support VDDQ prebias start-up
- SW1 and SW2 provides S3, S5 power control
- Optional external VLDOIN voltage for efficiency and flexible operation
- Convenient test points for probing critical waveforms

2 Electrical Performance Specifications

Table 1. TPS51916EVM-746 Electrical Performance Specifications

Parameter	Test Conditions	Min	Typ	Max	Units
Input Characteristics					
Voltage range	VIN	8	12	20	V
	V5IN	4.5	5	5.5	
Maximum input current	VIN = 8 V, I _{VDDQ} = 20 A		4.21		A
No-load input current	Vin = 20 V, I _{VDDQ} = 0 A		0.1		mA
VDDQ Output					
VDDQ Output voltage (VDDQSNS)	DDR3 (Default setting), R15 = 47.5k, R16 = 2k		1.5		V
	DDR2, R15 = R16= Open		1.8		V
	DDR3L, R15 = 28k, R16 = 2k		1.35		V
	DDR4, R15 = 18.2k, R16 = 2k		1.2		V
VDDQ Output voltage regulation	Line regulation (Vin = 8 V–20 V)		0.2%		
	Load regulation (Vin = 12 V, I _{VDDQ} = 0 A–20 A)		0.5%		
Output voltage ripple	Vin = 12 V, I _{VDDQ} = 20 A		20		mVpp
Output load current		0		20	A
Output overcurrent			30		A
Switching frequency			500		kHz
Peak efficiency	Vin = 12 V, 1.5 VDDQ/8 A		90.93%		
Full-load efficiency	Vin = 12 V, 1.5 VDDQ/20 A		87.3%		
VTT Output					
VTT output voltage			VTTREF		V
VTT output current	For DDR2(0.9 VTT) and DDR3(0.75 VTT)	–2		2	A
	For DDR3L(0.675 VTT) and DDR4(0.6 VTT)	–1.5		1.5	A
VTT output tolerance to VTTREF	I _{VTT} < 2 A, 1.4 V ≤ V _{VDDQSNS} ≤ 1.8 V	–40		40	mV
	I _{VTT} < 1.5 A, 1.2 V ≤ V _{VDDQSNS} < 1.4 V	–40		40	mV
VTTREF Output					
VTTREF output voltage			VDDQSNS/2		V
VTTREF output current		–10		10	mA

Table 1. TPS51916EVM-746 Electrical Performance Specifications (continued)

Parameter	Test Conditions	Min	Typ	Max	Units
VTTREF output tolerance to VDDQSNS	$ I_{V_{TTREF}} < 100 \mu A, 1.2 V \leq V_{VDDQSNS} \leq 1.8 V$	49.2%		50.8%	
	$ I_{V_{TTREF}} < 10 mA, 1.2 V \leq V_{VDDQSNS} < 1.8 V$	49%		51%	
Operating temperature			25		°C

3 Schematic

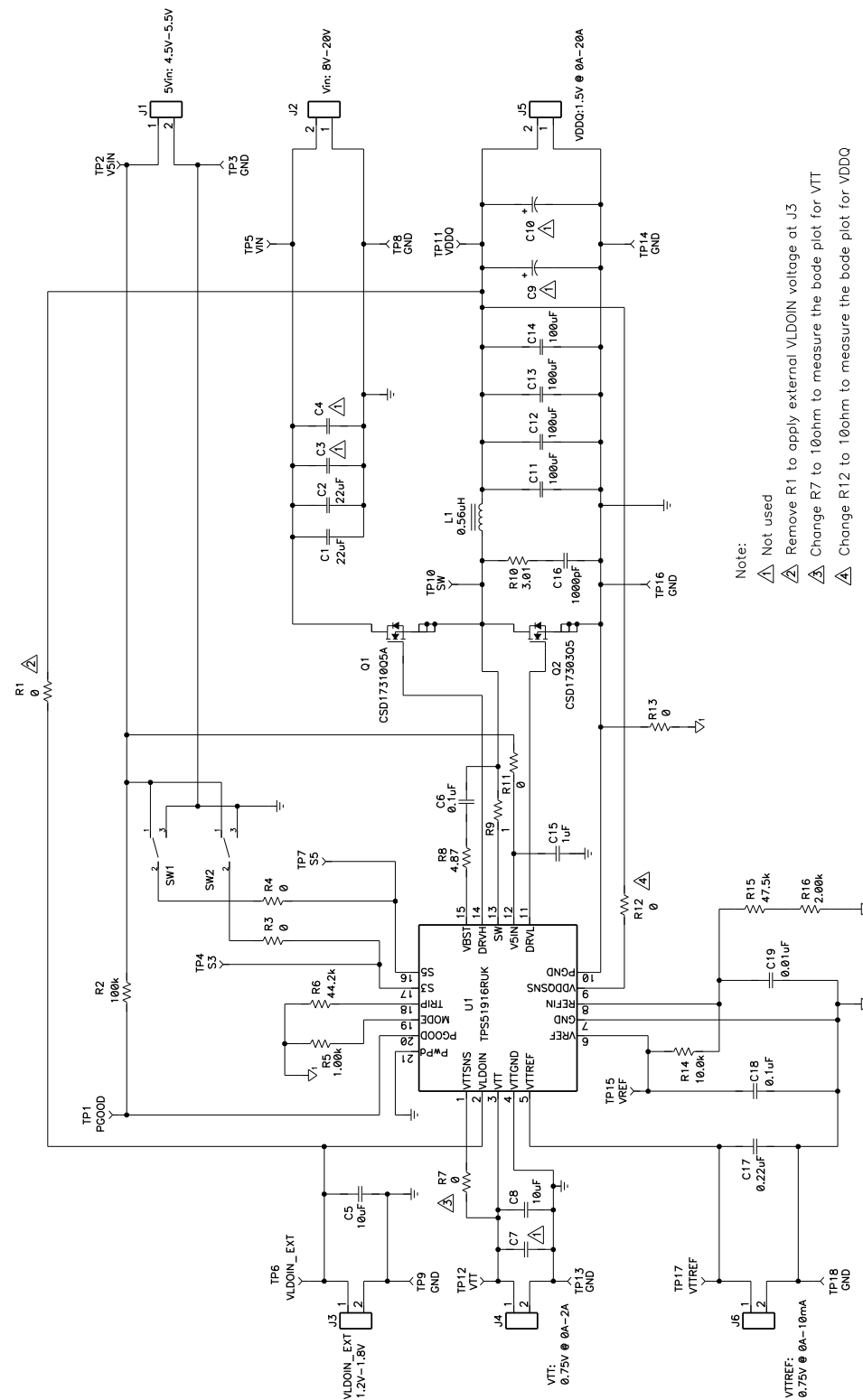


Figure 1. TPS51916EVM-746 Schematic

4 Test Setup

4.1 Test Equipment

Voltage Source V5IN: The input voltage source V5IN must be a 0-V to 5-V variable dc source capable of supplying 1 Adc. Connect V5IN to J1 as shown in [Figure 3](#).

Voltage Source VIN: The input voltage source VIN must be a 0-V to 20-V variable dc source capable of supplying 10 Adc. Connect VIN to J2 as shown in [Figure 3](#).

Multimeters:

- V1: V5IN at TP2 (V5IN) and TP3 (GND).
- V2: VIN at TP5 (VIN) and TP8 (GND).
- V3: VDDQ at TP11 (VDDQ) and TP14 (GND).
- V4: VTT at TP12 (VTT) and TP13 (GND).
- V5: VTTREF at TP17 (VTTREF) and TP18 (GND).
- A1: VIN input current
- A2: V5IN input current

Output Load: The output load must be an electronic constant-resistance mode load capable of 0-Adc to 20 Adc at 1.5 V.

Oscilloscope: A digital or analog oscilloscope can be used to measure the output ripple. The oscilloscope must be set for 1-M Ω impedance, 20-MHz bandwidth, ac coupling, 2- μ s/division horizontal resolution, 20-mV/division vertical resolution. Test points TP11 and TP14 can be used to measure the output ripple voltage by placing the oscilloscope probe tip through TP11 and holding the ground barrel on TP14 as shown in [Figure 2](#). Using a leaded ground connection may induce additional noise due to the large ground loop.

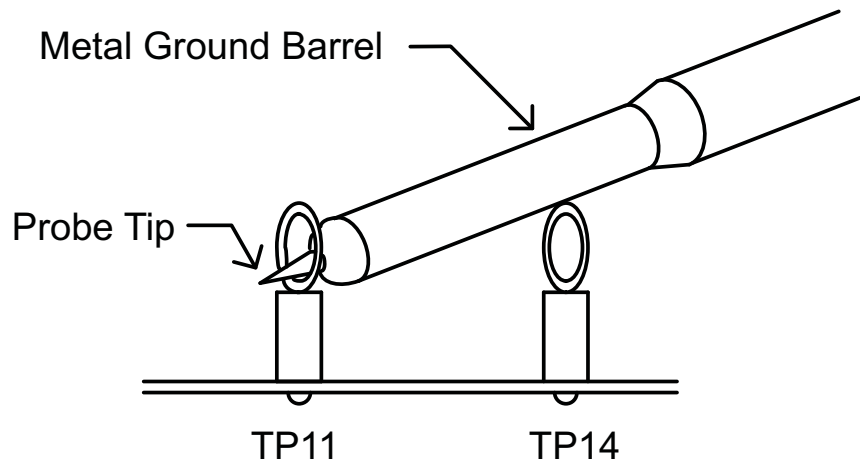


Figure 2. Tip and Barrel Measurement for VDDQ Output Ripple

Fan: Some of the components in this EVM may approach temperatures of 60°C during operation. A small fan capable of 200-400 LFM is recommended to reduce component temperatures while the EVM is operating. The EVM must not be probed if the fan is not running.

Recommended Wire Gauge:

1. V5IN to J1(5-V input):
The recommended wire size is 1x AWG 18 per input connection, with the total length of wire less than 4 feet (2-foot input, 2-foot return).
2. VIN to J2(12-V input):
The recommended wire size is 1x AWG 16 per input connection, with the total length of wire less than 4 feet (2-foot input, 2-foot return).
3. J5 to LOAD:
The minimum recommended wire size is 2x AWG 16, with the total length of wire less than 4 feet (2-foot input, 2-foot return)

4.2 Recommended Test Setup

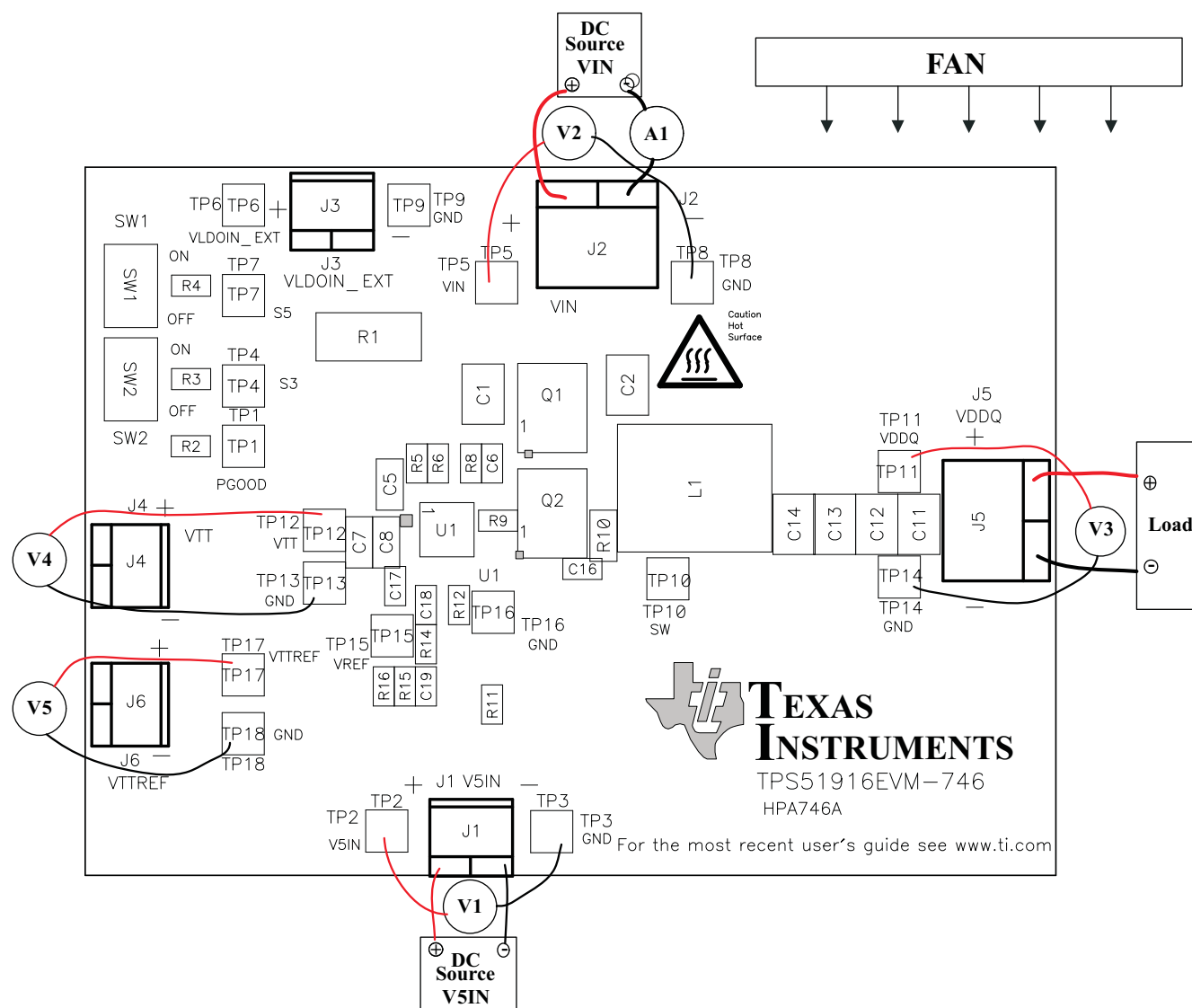


Figure 3. TPS51916EVM-746 Recommended Test Setup

Figure 3 is the recommended test setup to evaluate the TPS51916EVM-746. When working at an ESD workstation, ensure that any wrist straps, bootstraps, or mats are connected referencing the user to earth ground before power is applied to the EVM.

Input Connections:

1. Prior to connecting the dc source V5IN, it is advisable to limit the source current from V5IN to 1 A maximum. Ensure that V5IN is initially set to 0 V and connected as shown in Figure 3.
2. Prior to connecting the dc source VIN, it is advisable to limit the source current from VIN to 10 A maximum. Ensure that VIN is initially set to 0 V and connected as shown in Figure 3.
3. Connect voltmeters V1 at TP2 (V5IN) and TP3 (GND) to measure V5IN voltage, V2 at TP5 (VIN), and TP8 (GND) to measure VIN voltage as shown in Figure 3.
4. Connect a current meter A1 between dc source VIN and J2 to measure the input current.
5. Connect a current meter A2 between dc source V5IN and J1 to measure the input current.

Output Connections:

1. Connect the load to J5 and set the load to constant-resistance mode to sink 0 Adc before V5IN and VIN are applied.
2. Connect a voltmeter V3 at TP11 (VDDQ) and TP14 (GND) to measure VDDQ voltage, V4 at TP12 (VTT) and TP13 (GND) to measure VTT voltage and V5 at TP17 (VTTREF) and TP18 (GND) to measure VTTREF voltage.

Other Connections:

Place a fan as shown in [Figure 3](#) and turn it on, ensuring that air is flowing across the EVM.

5 Configurations

5.1 S3, S5 Enable Selection

The controller can be enabled and disabled by switches SW1 and SW2.

Default setting: Push SW1 and SW2 to the bottom (OFF position) to disable the controller.

Table 2. S3, S5 Enable Selection

State	SW2 (S3) set to	SW1(S5) set to	VDDQ	VTTREF	VTT
S0	ON position	ON position	ON	ON	ON
S3	OFF position	ON position	ON	ON	OFF(High-Z)
S4/S5	OFF position	OFF position	OFF(Discharge)	OFF(Discharge)	OFF(Discharge)

6 Test Procedure

6.1 Line/Load Regulation and Efficiency Measurement Procedure

1. Set up EVM as described in [Section 4](#) and [Figure 3](#).
2. Ensure that the load is set to constant-resistance mode and to sink 0 Adc.
3. Ensure that SW1 and SW2 are in the OFF position.
4. Increase V5IN from 0 V to 5 V. Use V1 to measure V5IN input voltage.
5. Increase VIN from 0 V to 12 V. Use V2 to measure VIN input voltage.
6. Push SW1 and SW2 to ON position to enable the controller.
7. Use V3 to measure VDDQ output voltage.
8. Use V4 to measure VTT output voltage.
9. Use V5 to measure VTTREF output voltage.
10. Use A1 to measure VIN input current for efficiency.
11. Use A2 to measure V5IN input current for efficiency.
12. Vary the load from 0 Adc to 20 Adc; VDDQ must remain in load regulation.
13. Vary VIN from 8 V to 20 V; VDDQ must remain in line regulation.
14. Push SW1 and SW2 to OFF position to disable the controller.
15. Decrease the load to 0 A.
16. Decrease VIN and V5IN to 0 V.

6.2 List of Test Points

Table 3. Test Point Functions

Test Points	Name	Description
TP1	PGOOD	Power Good
TP2	V5IN	5-V input
TP3	GND	Ground

Table 3. Test Point Functions (continued)

Test Points	Name	Description
TP4	S3	S3 signal input
TP5	VIN	VIN input
TP6	VLDOIN_EXT	External input for VLDOIN
TP7	S5	S5 signal input
TP8	GND	Ground
TP9	GND	Ground
TP10	SW	Switching node
TP11	VDDQ	VDDQ output
TP12	VTT	VTT output
TP13	GND	Ground
TP14	GND	Ground
TP15	VREF	Internal 1.8-V reference voltage
TP16	GND	Ground
TP17	VTTREF	Buffered VTT reference voltage
TP18	GND	Ground

6.3 Equipment Shutdown

1. Shut down the load.
2. Shut down V5IN and VIN.
3. Shut down the fan.

7 Performance Data and Typical Characteristic Curves

Figure 4 through Figure 22 present typical performance curves for TPS51916EVM-746.

7.1 DDR3 VDDQ Efficiency

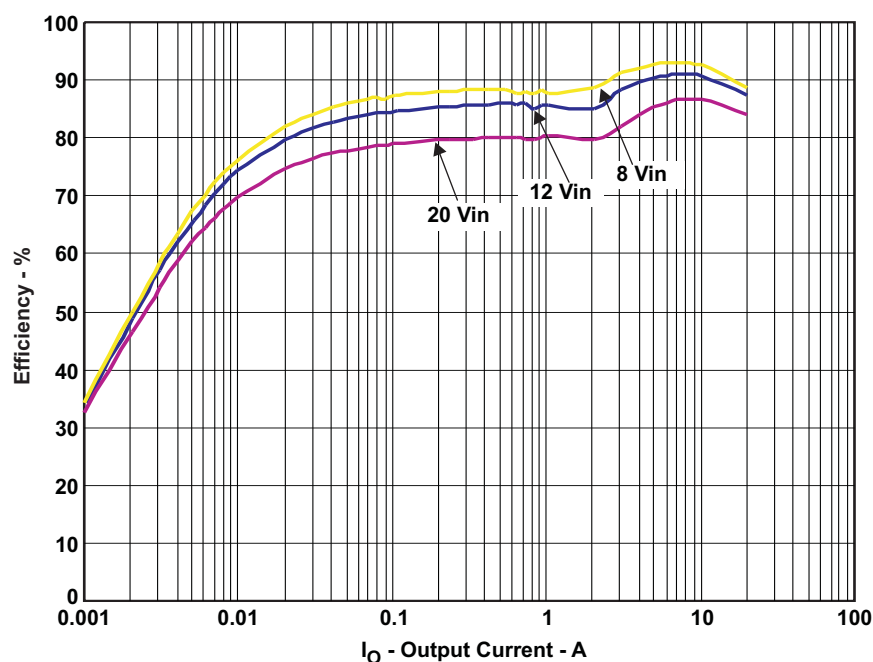


Figure 4. DDR3 VDDQ Efficiency

7.2 DDR3 VDDQ Load Regulation

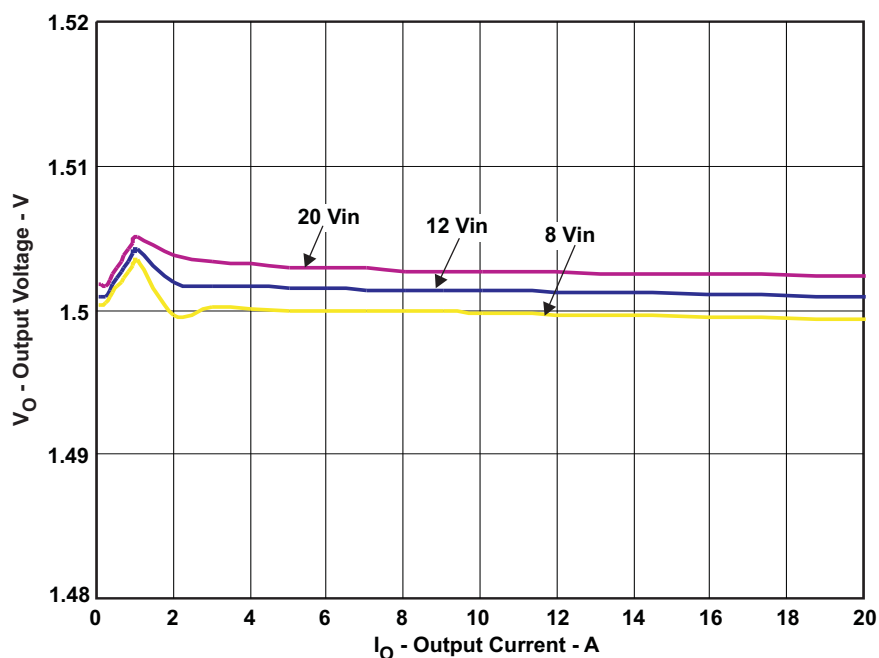


Figure 5. DDR3 VDDQ Load Regulation

7.3 DDR3 VDDQ Line Regulation

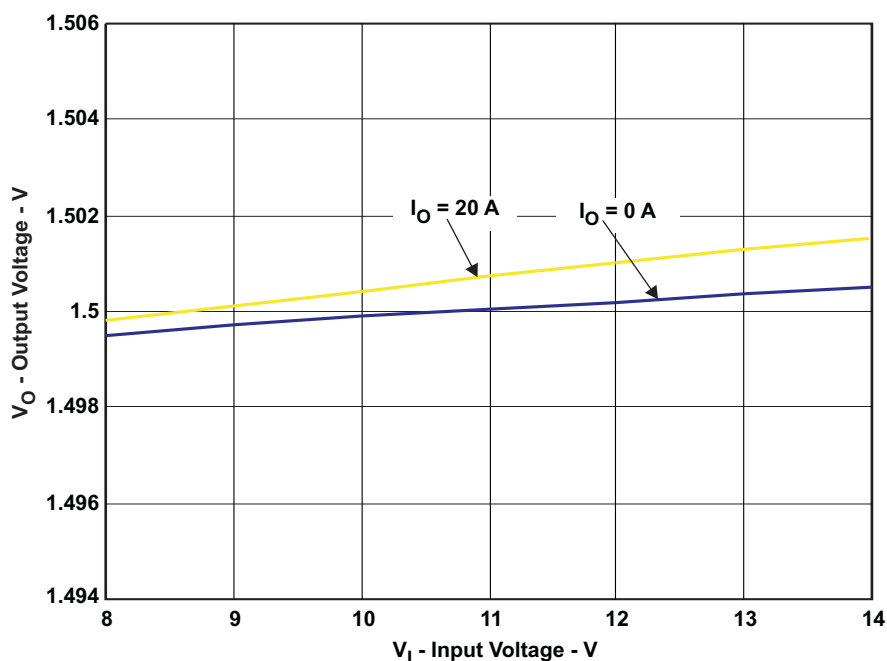


Figure 6. DDR3 VDDQ Line Regulation

7.4 DDR3 VTT Load Regulation

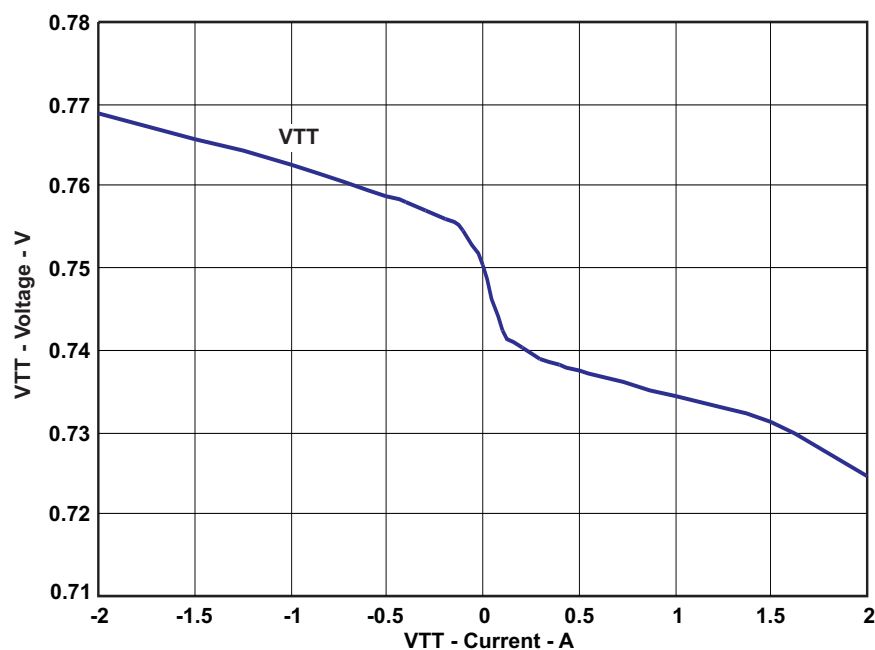


Figure 7. DDR3 VTT Load Regulation

7.5 DDR3 VTTREF Load Regulation

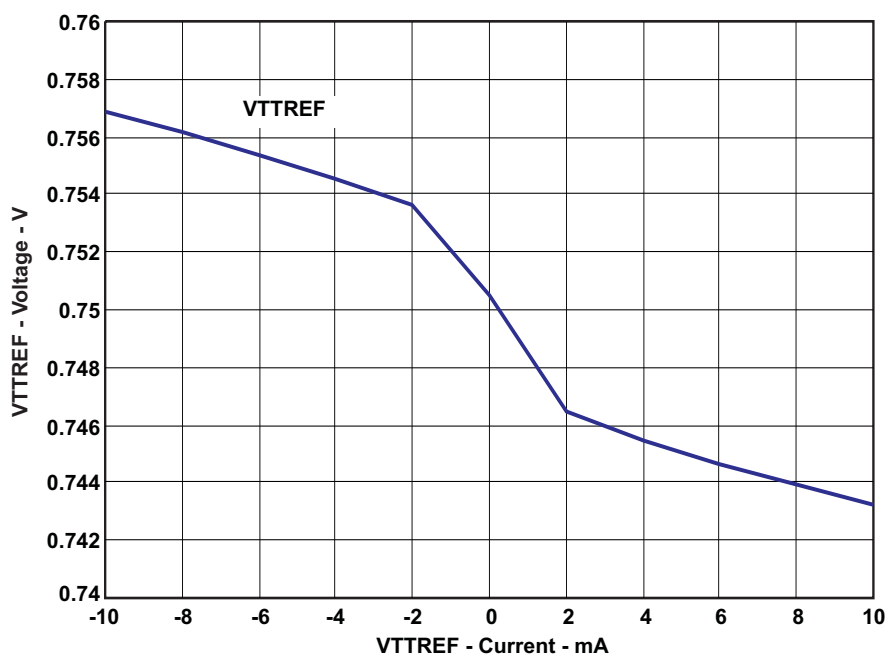


Figure 8. DDR3 VTTREF Load Regulation

7.6 DDR3 VTT Dropout Voltage

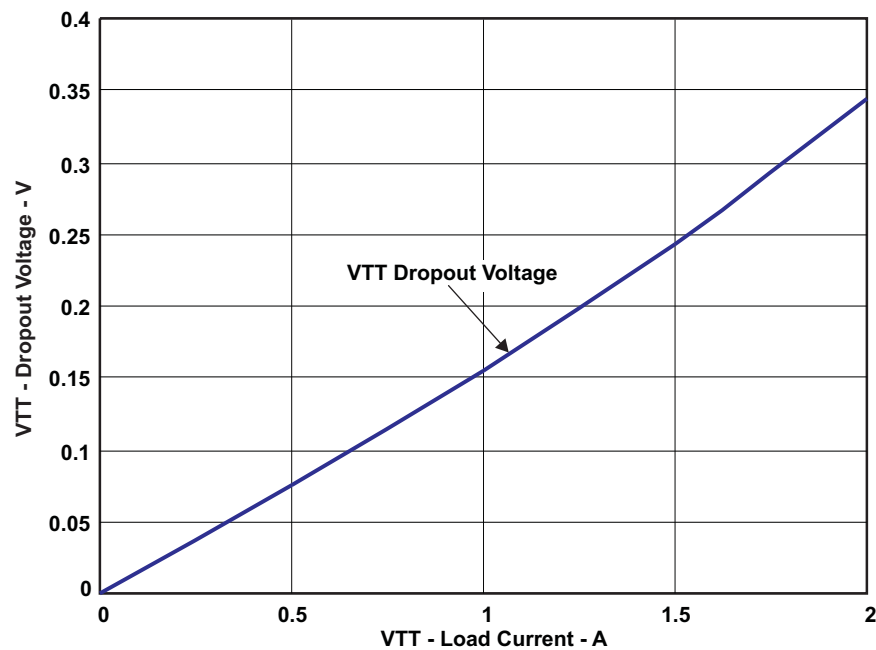


Figure 9. DDR3 VTT Dropout Voltage

7.7 DDR3 S5 Enable Turnon/Turnoff

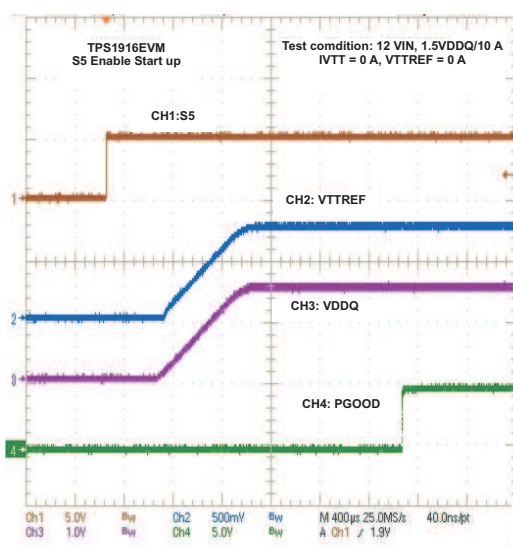


Figure 10. DDR3 S5 Enable Turnon

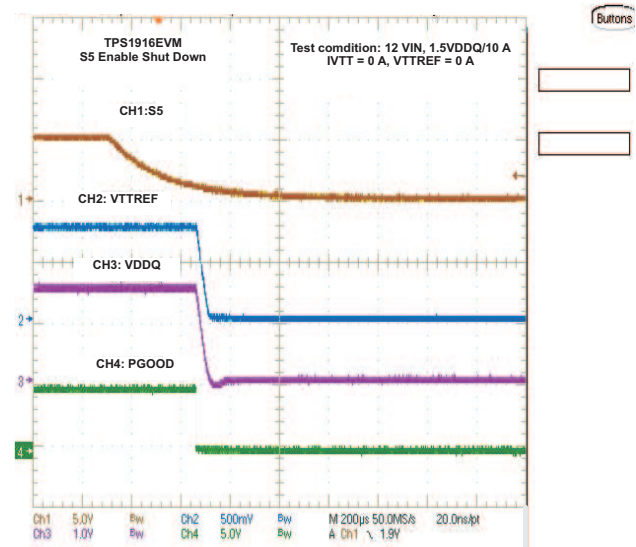


Figure 11. DDR3 S5 Enable Turnoff

7.8 S5 Enable Turnon with 1-V Prebias at VDDQ

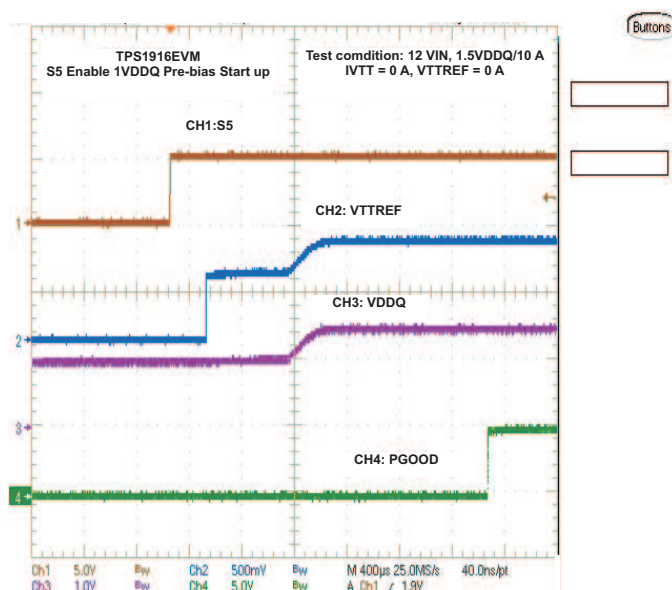


Figure 12. DDR3 S5 Enable Turnon With 1-V Prebias at VDDQ

7.9 DDR3 S3 Enable Turnon/ Turnoff (S5 is ON)

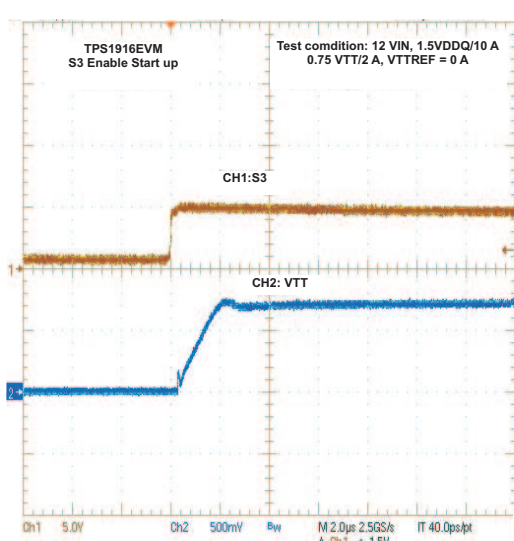


Figure 13. DDR3 S3 Enable Turnon

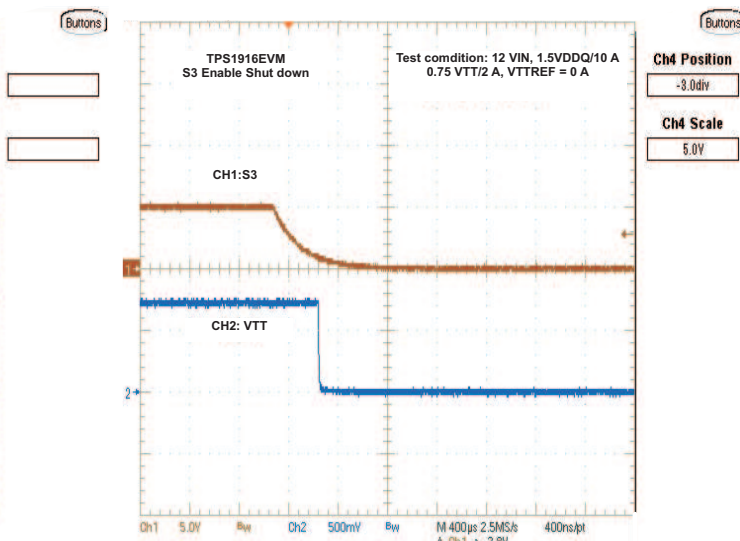


Figure 14. DDR3 S3 Enable Turnoff

7.10 DDR3 VDDQ Output Ripple

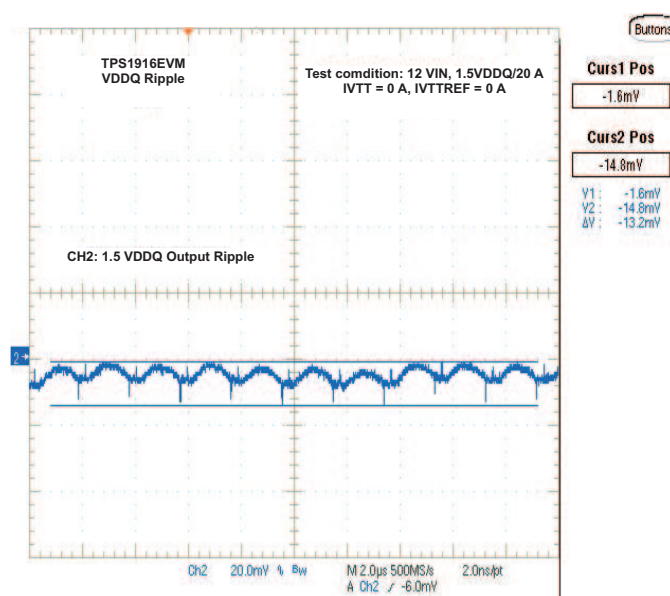


Figure 15. DDR3 VDDQ Output Ripple

7.11 DDR3 VDDQ Switching Node

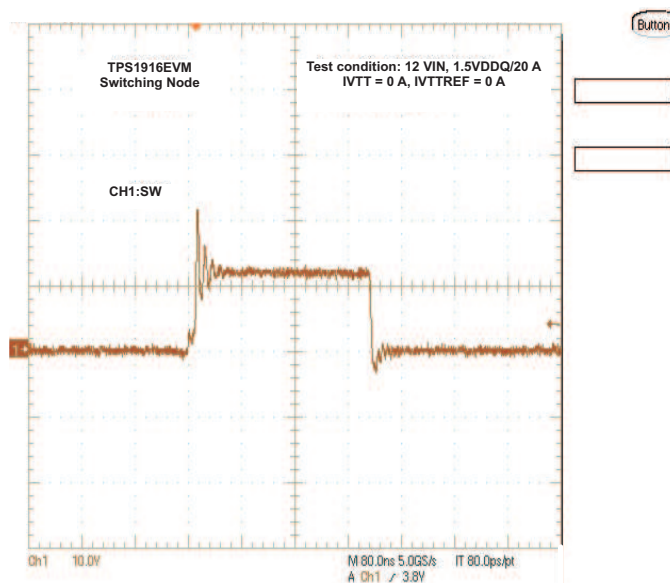


Figure 16. DDR3 VDDQ Switching Node

7.12 DDR3 VDDQ Output Transient

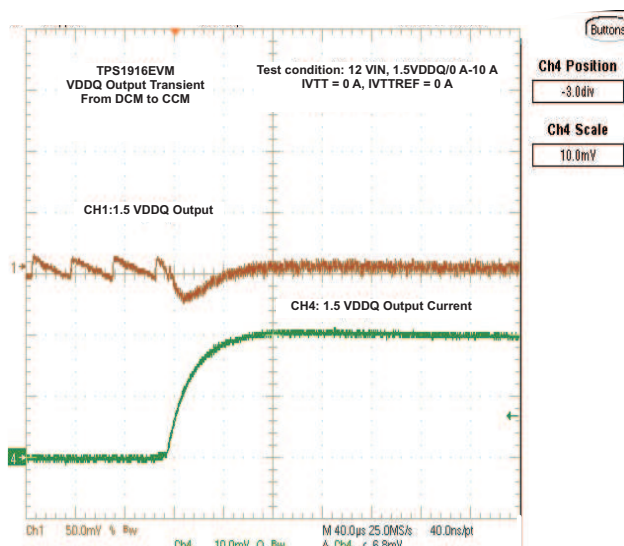


Figure 17. VDDQ Output Transient From DCM to CCM

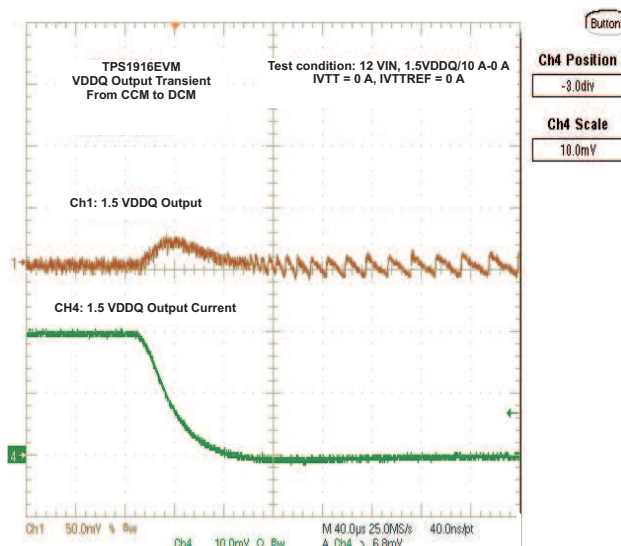


Figure 18. VDDQ Output Transient From CCM to DCM

7.13 DDR3 VTT Transient With 1.5-A Sinking and Sourcing Current

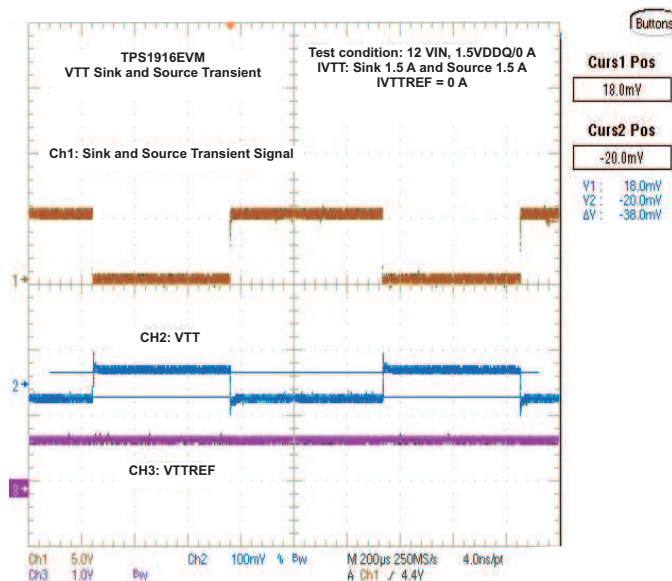


Figure 19. DDR3 VTT Transient With 1.5-A Sinking and Sourcing Current

7.14 Thermal Image

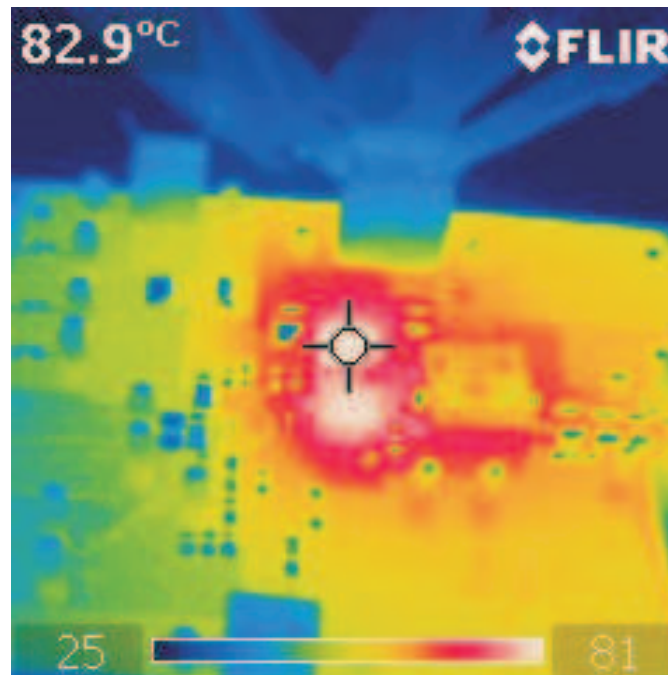


Figure 20. Top Board at 12 Vin, 1.5 VDDQ/20 A, No Load at VTT, 25°C Ambient Without Airflow

7.15 DDR3 VDDQ Bode Plot



Figure 21. DDR3 VDDQ Bode Plot at 12 Vin, 1.5 VDDQ/10 A

7.16 DDR3 VTT Bode Plot



Figure 22. DDR3 VTT Bode Plot at 12 Vin, 1.5 VDDQ/0 A and VTT 1-A Sourcing

8 EVM Assembly Drawing and PCB Layout

The following figures (Figure 23 through Figure 28) show the design of the TPS51916EVM-746 printed-circuit board (PCB). The EVM has been designed using a 4-layer, 2-oz copper circuit board.

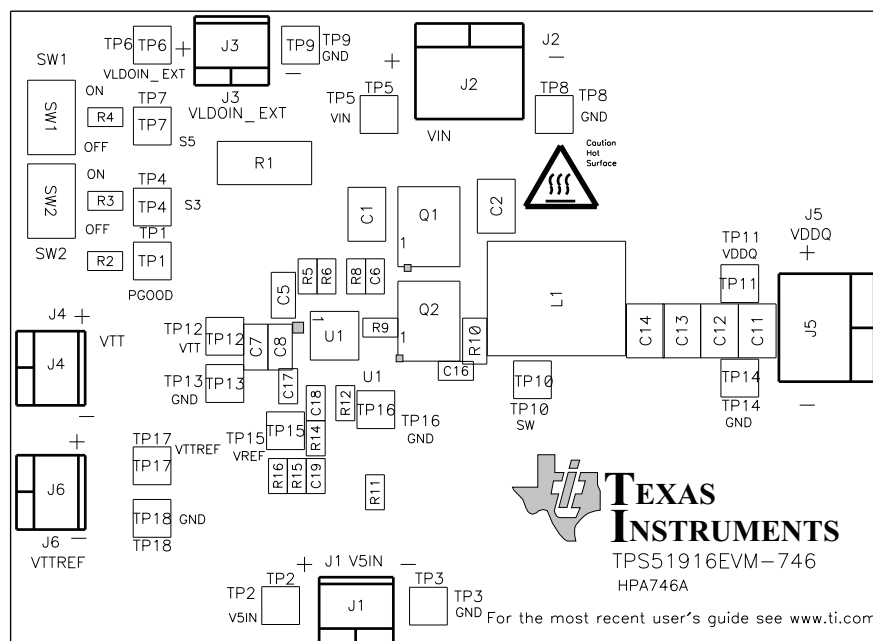


Figure 23. TPS51916EVM-746 Top Layer Assembly Drawing

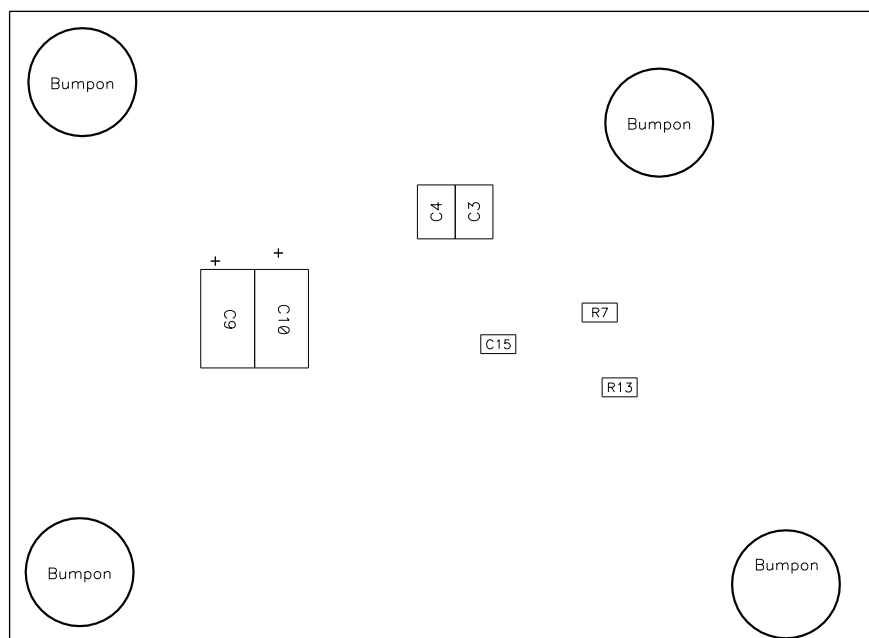


Figure 24. TPS51916EVM-746 Bottom Assembly Drawing

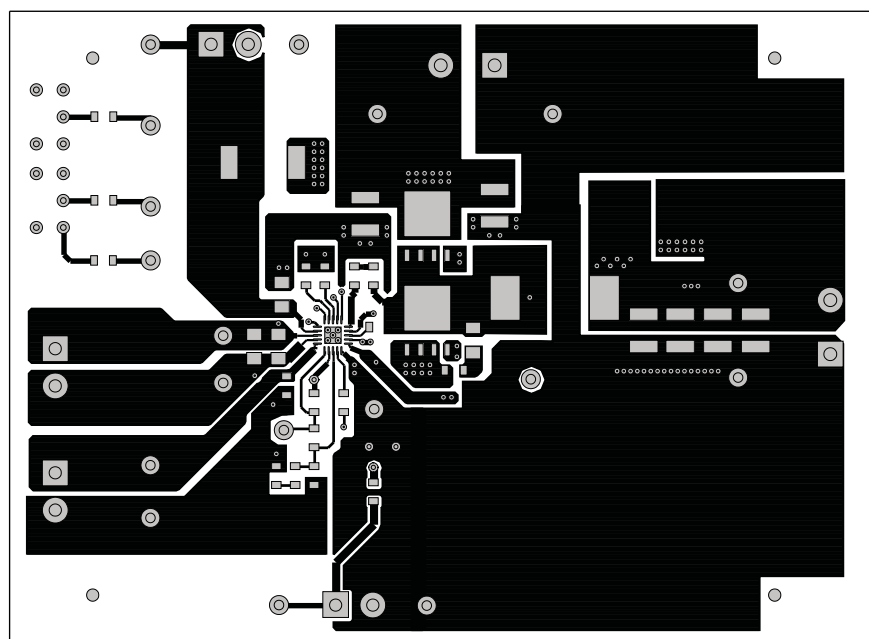


Figure 25. TPS51916EVM-746 Top Copper

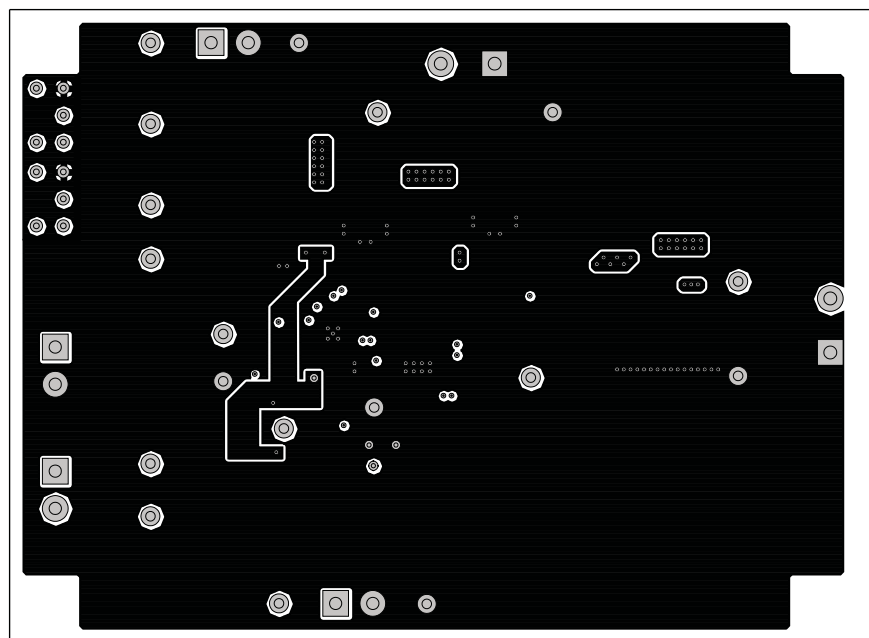


Figure 26. TPS51916EVM-746 Layer-2 Copper

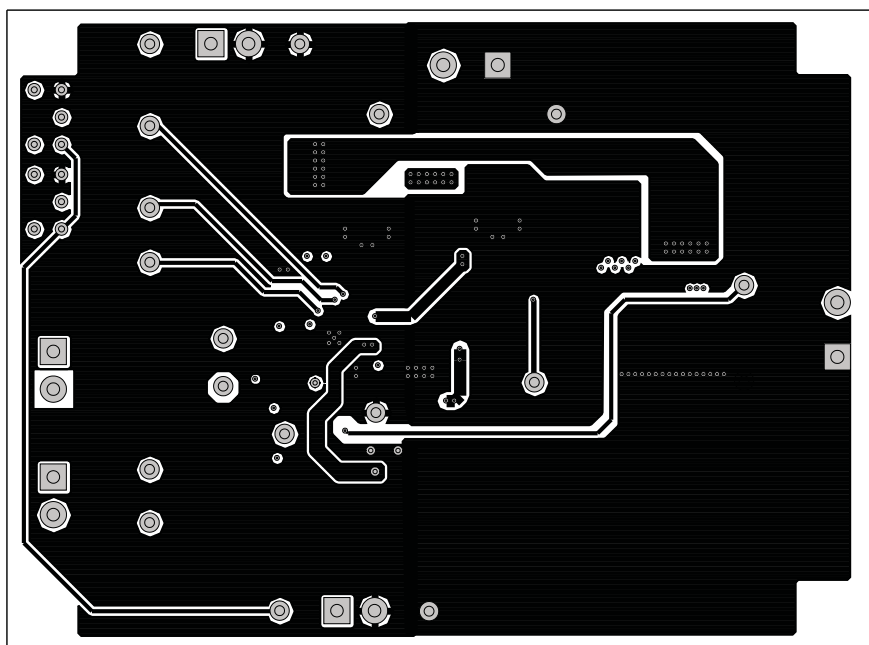


Figure 27. TPS51916EVM-746 Layer-3 Copper

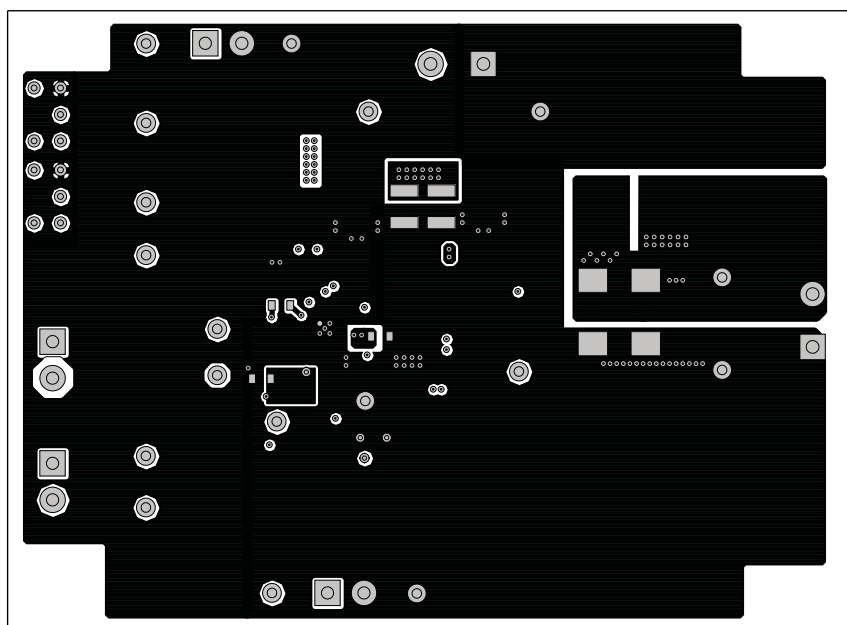


Figure 28. TPS51916EVM-746 Bottom Copper

9 Bill of Materials

Table 4. TPS51916EVM-746 Bill of Materials

QTY	REFDES	DESCRIPTION	MFR	PART NUMBER
2	C1, C2	Capacitor, Ceramic, 22 μ F, 25V, X5R, 20%, 1210	MURATA	GRM32ER61C226KE20L
4	C11, C12, C13, C14	Capacitor, Ceramic, 100 μ F, 6.3V, X5R, 20%, 1210	MURATA	GRM32ER60J107ME20L
1	C15	Capacitor, Ceramic, 1 μ F, 25V, X7R, 20%, 0603	STD	STD
1	C16	Capacitor, Ceramic, 1000 μ F, 50V, X7R, 20%, 0603	STD	STD
1	C17	Capacitor, Ceramic, 0.22 μ F, 25V, X7R, 20%, 0603	STD	STD
1	C19	Capacitor, Ceramic, 0.01 μ F, 25V, X7R, 20%, 0603	STD	STD
2	C5, C8	Capacitor, Ceramic, 10 μ F, 10V, X5R, 20%, 0805	STD	STD
2	C6, C18	Capacitor, Ceramic, 0.1 μ F, 50V, X7R, 20%, 0603	STD	STD
1	Q1	MOSFET, N-ch, 30V, 21A, 4.5 m Ω	TI	CSD17310Q5A
1	Q2	MOSFET, N-ch, 30V, 32A, 2.0 m Ω	TI	CSD17303Q5
1	L1	Inductor, SMT, 0.56 μ H, 21A, 1.56 m Ω , 0.510"x0.520"	Panasonic	ETQP4LR56WFC
1	R1	Resistor, Chip, 0, 1W, 1%, 2512	STD	STD
1	R10	Resistor, Chip, 3.01, 1/16W, 1%, 0805	STD	STD
1	R14	Resistor, Chip, 10.0k, 1/16W, 1%, 0603	STD	STD
1	R15	Resistor, Chip, 47.5k, 1/16W, 1%, 0603	STD	STD
1	R16	Resistor, Chip, 2.00k, 1/16W, 1%, 0603	STD	STD
1	R2	Resistor, Chip, 100k, 1/16W, 1%, 0603	STD	STD
1	R5	Resistor, Chip, 1.00k, 1/16W, 1%, 0603	STD	STD
1	R6	Resistor, Chip, 44.2k, 1/16W, 1%, 0603	STD	STD
1	R8	Resistor, Chip, 4.87, 1/16W, 1%, 0603	STD	STD
1	R9	Resistor, Chip, 1, 1/16W, 1%, 0603	STD	STD
6	R3, R4, R7, R11, R12, R13	Resistor, Chip, 0, 1/16W, 1%, 0603	STD	STD
1	U1	IC, Complete DDR2, DDR3 and DDR3L Memory Power Solution, RUK-20	TI	TPS51916RUK

Evaluation Board/Kit Important Notice

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